TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

SSM6K06FU

High Speed Switching Applications

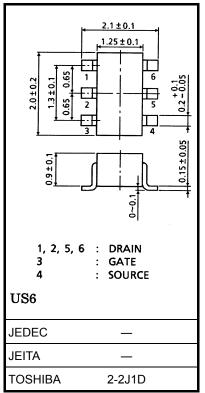
- Small package
- Low on resistance: $R_{on} = 160 \text{ m}\Omega \text{ max} (@V_{GS} = 4 \text{ V})$

 $: R_{on} = 210 \text{ m}\Omega \text{ max} (@V_{GS} = 2.5 \text{ V})$

• Low gate threshold voltage

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V _{DS}	20	V	
Gate-source voltage		V _{GSS}	±12	V	
Drain current	DC	۱ _D	1.1	A	
	Pulse	I _{DP}	2.2		
Drain power dissipation (Ta = 25°C)		P _D (Note 1)	300	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	



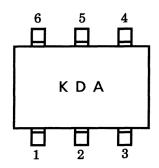
Weight: 6.8 mg (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

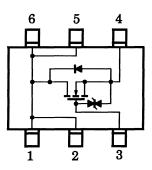
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on FR4 board. (25.4 mm \times 25.4 mm \times 1.6 t, Cu pad: 0.32 mm² \times 6) Figure 1.

Marking



Equivalent Circuit (top view)



Handling Precaution

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

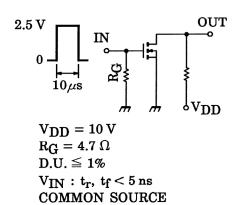
Unit: mm

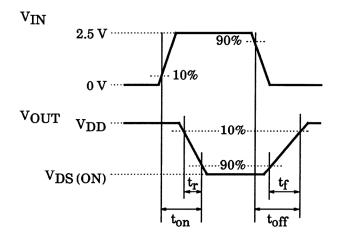
Electrical Characteristics (Ta = 25°C)

Chara	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage curr	ent	I _{GSS}	$V_{GS}=\pm 12~V,~V_{DS}=0$	_	_	±1	μA
Drain-source brea	kdown voltage	V (BR) DSS	$I_D = 1 \text{ mA}, V_{GS} = 0$	20	_		V
Drain cut-off curre	nt	I _{DSS}	$V_{DS} = 20 V, V_{GS} = 0$	_	_	1	μA
Gate threshold vo	Itage	V _{th}	$V_{DS} = 3 V, I_D = 0.1 mA$	0.6	_	1.1	V
Forward transfer a	admittance	Y _{fs}	$V_{DS} = 3 V, I_D = 0.5 A$ (Note 2)	1.2	_		S
Drain-source ON resistance		R _{DS (ON)}	$I_D = 0.5 \text{ A}, V_{GS} = 4 \text{ V}$ (Note 2	—	120	160	mΩ
			$I_D = 0.5 \text{ A}, V_{GS} = 2.5 \text{ V}$ (Note 2	—	160	210	
Input capacitance	capacitance C_{iss} $V_{DS} = 10 V$, $V_{GS} = 0$, f = 1 MHz		_	125		pF	
Reverse transfer of	capacitance	C _{rss}	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ MHz}$		30		pF
Dutput capacitance C_{OSS} $V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ MHz}$		_	75		pF		
Switching time	Turn-on time	t _{on}	V_{DD} = 10 V, I_D = 0.5 A, V_{GS} = 0~2.5 V, R_G = 4.7 Ω	_	42		ns
	Turn-off time	t _{off}		_	100		

Note 2: Pulse test

Switching Time Test Circuit





Precaution

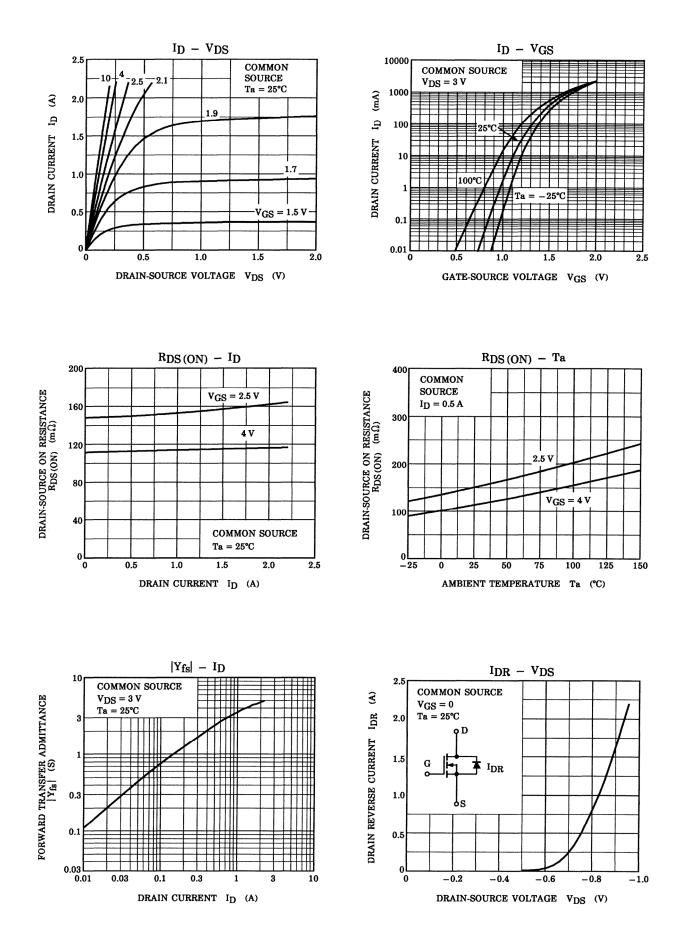
 $Ta = 25^{\circ}C$

 V_{th} can be expressed as voltage between gate and source when low operating current value is I_D = 100 μA for this product. For normal switching operation, V_{GS} (on) requires higher voltage than V_{th} and V_{GS} (off) requires lower voltage than V_{th} .

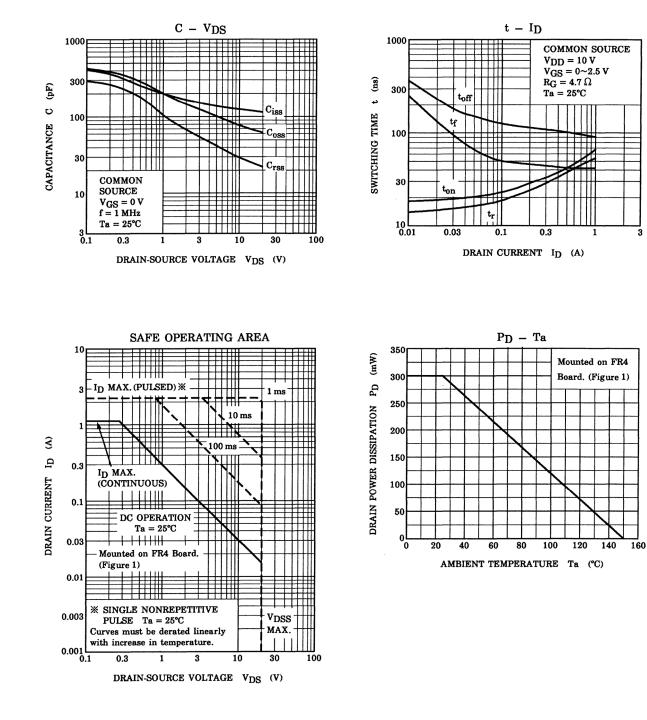
(Relationship can be established as follows: $V_{GS} \ (off) < V_{th} < V_{GS} \ (on))$

Please take this into consideration for using the device.

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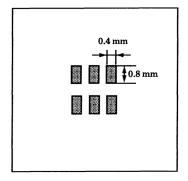


Figure 1 25.4 mm \times 25.4 mm \times 1.6 t, Cu Pad: 0.32 mm² \times 6

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20070701-EN GENERAL

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